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1774

THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Appln. Of:

ANDRE et al.

Serial No.:

09/830,380

Filed:

April 25, 2001

For:

THIN LAYER OF HAFNIUM OXIDE AND DEPOSIT PROCESS

Group:

1774

Examiner:

T. Dicus

DOCKET: BREV 13186

Assistant Commissioner of Patents and Trademarks Washington, D.C. 20231

AMENDMENT B

RECEIVED

DEC 1-1 2002

TC 1700

Dear Sir:

This amendment is being filed in response to the Official Action mailed October 4, 2002.

Please amend the application as follows:

IN THE SPECIFICATION:

Please replace the sub-paragraph beginning on page 14, line 15, with the following rewritten paragraph:

A1

-- Figure 3 between a layer of hafnium oxide comprising crystals of hafnium oxide resulting from ion bombardment of the substrate and an amorphous layer according to the invention.--

Please replace the sub-paragraph beginning on page 14, line 23, with the following 'rewritten paragraph:

HAYES SOLOWAY P.C.

130 W. CUSHING ST. TUCSON AZ 85701 TEL. 320.882.7623 -- - Figure 5 is a curve representing the reflection of a mirror component of Figure 4 in function of wavelength.--

,,o. 020.002.,

175 CANAL STREET MANCHESTER, NH 03101 TEL. 603.668.1400 FAX. 603.668.8567 Please replace the paragraph beginning on page 15, line 15, with the following rewritten paragraph: